

Toshiyuki Kawaharamura

List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/1998254/publications.pdf>

Version: 2024-02-01

17
papers

598
citations

933447

10
h-index

940533

16
g-index

17
all docs

17
docs citations

17
times ranked

516
citing authors

#	ARTICLE	IF	CITATIONS
1	Growth of Crystalline Zinc Oxide Thin Films by Fine-Channel-Mist Chemical Vapor Deposition. Japanese Journal of Applied Physics, 2008, 47, 4669.	1.5	109
2	Stoichiometry Control of ZnO Thin Film by Adjusting Working Gas Ratio during Radio Frequency Magnetron Sputtering. Journal of Materials, 2013, 2013, 1-6.	0.1	95
3	Physics on development of open-air atmospheric pressure thin film fabrication technique using mist droplets: Control of precursor flow. Japanese Journal of Applied Physics, 2014, 53, 05FF08.	1.5	93
4	Linear-Source Ultrasonic Spray Chemical Vapor Deposition Method for Fabrication of ZnMgO Films and Ultraviolet Photodetectors. Japanese Journal of Applied Physics, 2006, 45, L857-L859.	1.5	87
5	Low-Temperature Growth of ZnO Thin Films by Linear Source Ultrasonic Spray Chemical Vapor Deposition. Japanese Journal of Applied Physics, 2007, 46, 6811-6813.	1.5	65
6	Porosity-tuned thermal conductivity in thermoelectric Al-doped ZnO thin films grown by mist-chemical vapor deposition. Thin Solid Films, 2019, 685, 180-185.	1.8	38
7	Growth and electrical properties of AlO _x grown by mist chemical vapor deposition. AIP Advances, 2013, 3, .	1.3	30
8	\hat{I}_{\pm} -(Al _x Ga _{1-\hat{x}}) ₂ O ₃ single-layer and heterostructure buffers for the growth of conductive Sn-doped \hat{I}_{\pm} -Ga ₂ O ₃ thin films via mist chemical vapor deposition. APL Materials, 2020, 8, .	5.1	15
9	Conductive Si-doped \hat{I}_{\pm} -(Al _x Ga _{1-\hat{x}}) ₂ O ₃ thin films with the bandgaps up to 6.22 eV. AIP Advances, 2020, 10, 115019.	1.3	13
10	Growth mechanism of zinc oxide thin film by mist chemical vapor deposition via the modulation of [H ₂ O]/[Zn] ratios. Applied Physics Express, 2019, 12, 065505.	2.4	10
11	Composition control of Zn _{1-x} Mg _x O thin films grown using mist chemical vapor deposition. Japanese Journal of Applied Physics, 2019, 58, 035503.	1.5	10
12	Fabrication of Silicon Oxide Thin Films by Mist Chemical Vapor Deposition Method from Polysilazane and Ozone as Sources. Japanese Journal of Applied Physics, 2012, 51, 090201.	1.5	10
13	Optical Characterization of Gallium Oxide \hat{I}_{\pm} and \hat{I}^2 Polymorph Thin-Films Grown on c-Plane Sapphire. Journal of Electronic Materials, 2021, 50, 2990-2998.	2.2	9
14	The effect of HCl on the \hat{I}_{\pm} -Ga ₂ O ₃ thin films fabricated by third generation mist chemical vapor deposition. AIP Advances, 2021, 11, 045123.	1.3	7
15	The Quality Improvement of Yttrium Oxide Thin Films Grown at Low Temperature via the Third-Generation Mist Chemical Vapor Deposition Using Oxygen-Supporting Sources. Physica Status Solidi (B): Basic Research, 2021, 258, 2100105.	1.5	5
16	Mist chemical vapor deposition study of 20 and 100 nm thick undoped ferroelectric hafnium oxide films on n+-Si(100) substrates. Japanese Journal of Applied Physics, 2019, 58, SLLB10.	1.5	2
17	Development of "Mist CVD", Functional Thin Film Fabrication Techniques Utilizing Mist Flow. Hyomen Cijutsu/Journal of the Surface Finishing Society of Japan, 2017, 68, 707-711.	0.2	0